

A roadmap for electronic grade 2D materials

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2-dimensional materials hold promise for next-generation electronics. However, in order to realize 2D-based technologies, key milestones must be identified and met. This article identifies areas of research which are fundamentally required for achieving electronic grade 2D materials and brings together experts in these respective areas to discuss key challenges. As a result, this article serves as a roadmap for the realization of 2D materials which can be used in the development of technology toward industries including healthcare, internet of things, high-performance computing, and economical solar energy.

This article can serve as a guide, and a source of inspiration and motivation for researchers and members of the 2D community. Additionally, it communicates the importance of 2D research to the greater scientific community, as well as industry players, demonstrating the current and potential impact of these materials on technology and society.

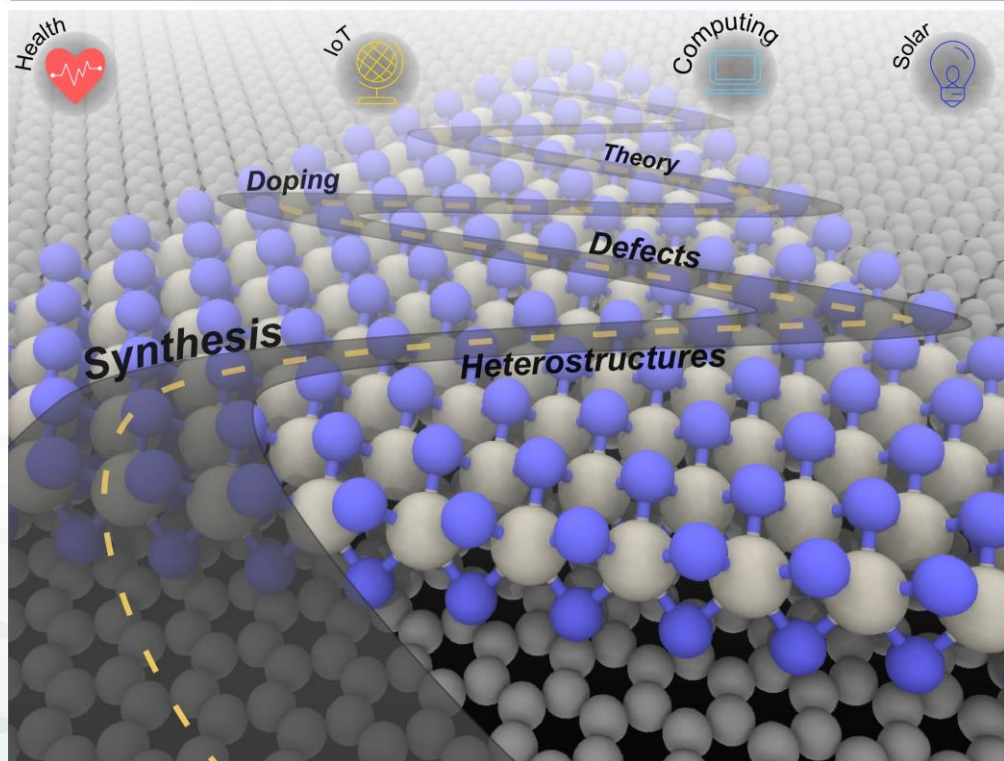


Image credit: Natalie Briggs

Visualization and analysis of atomistic simulation data with OVITO

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